NSN 5961-00-828-2500

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Inclosure Material:

Glass and metal

Overall Length:

0.330 inches

Overall Diameter:

0.675 inches

Mounting Facility Quantity:

4

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 100.0 breakdown voltage, collector-to-emitter, base open and 8.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

5.00 amperes source cutoff current

Power Rating Per Characteristic:

60.0 watts small-signal input power, common-collector

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 tab, solder lug

Specification Data:

80131-release3225 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0